

# HAT2185WP

## Silicon N Channel Power MOS FET Power Switching

REJ03G1744-0200

Rev.2.00

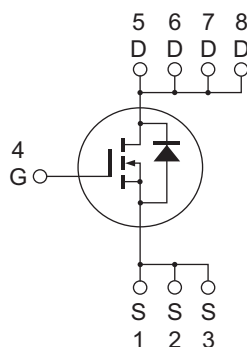
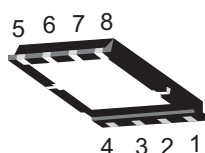
Nov 28, 2008

### Features

- Low on-resistance
- Low drive current
- High density mounting

### Outline

RENESAS Package code: PWSN0008DA-A  
(Package name: WPAK)



1, 2, 3 Source  
4 Gate  
5, 6, 7, 8 Drain

### Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	150	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	$I_D$	10	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	20	A
Body-drain diode reverse drain current	$I_{DR}$	10	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	20	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	10	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	7.5	mJ
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	20	W
Channel to case thermal impedance	$\theta_{ch-c}$	6.25	°C/W
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Notes: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$

2. Value at  $T_c = 25^\circ C$

3.  $STch = 25^\circ C$ ,  $T_{ch} \leq 150^\circ C$

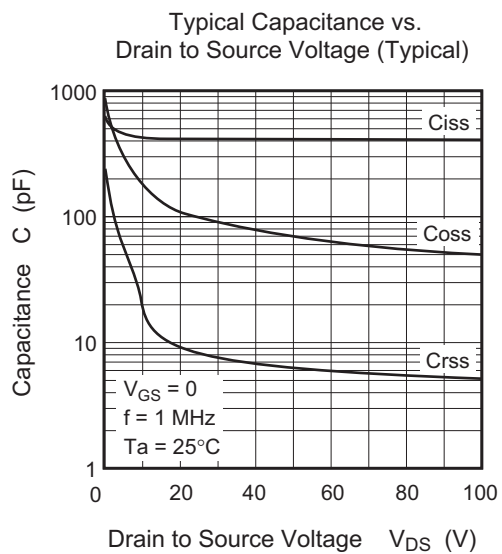
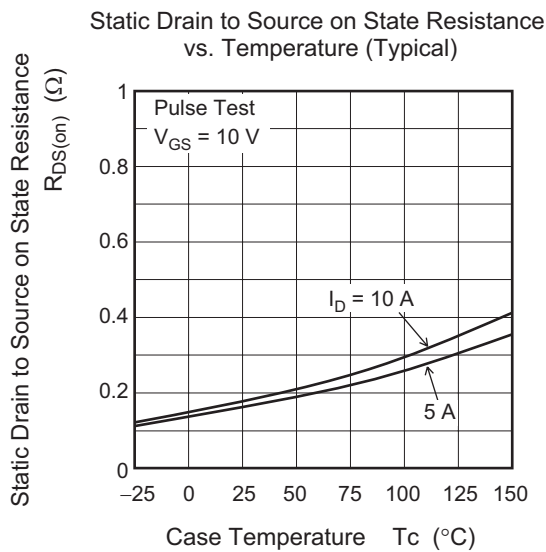
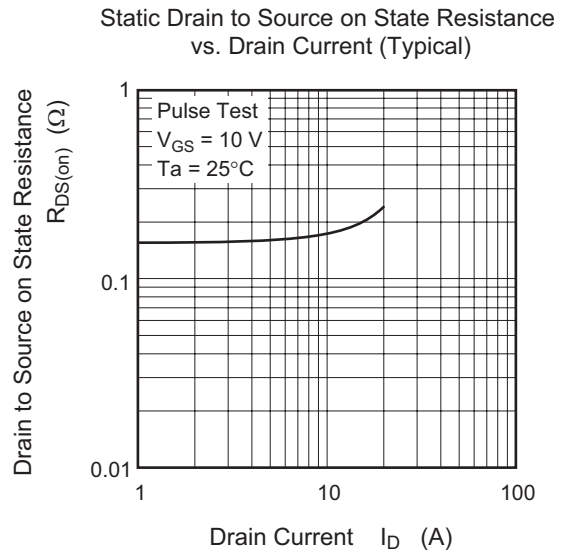
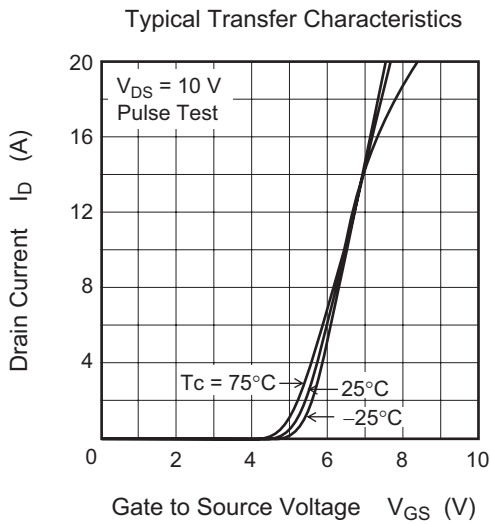
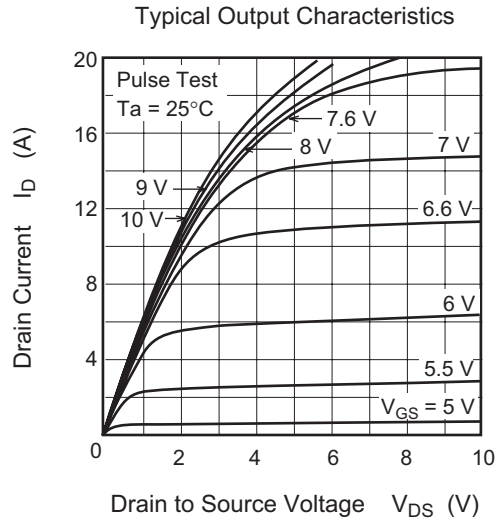
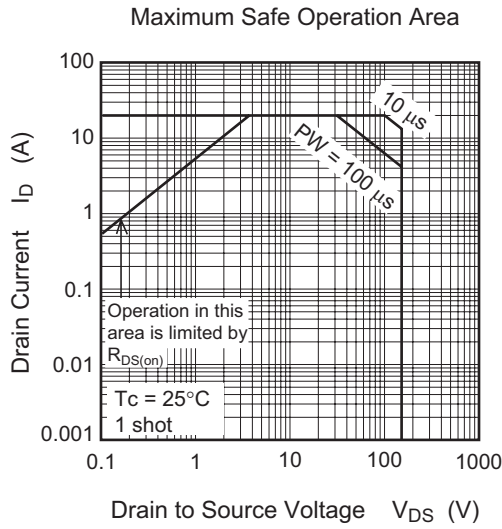
## Electrical Characteristics

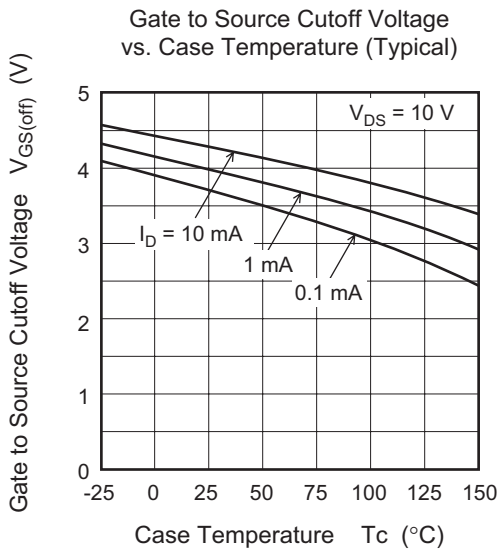
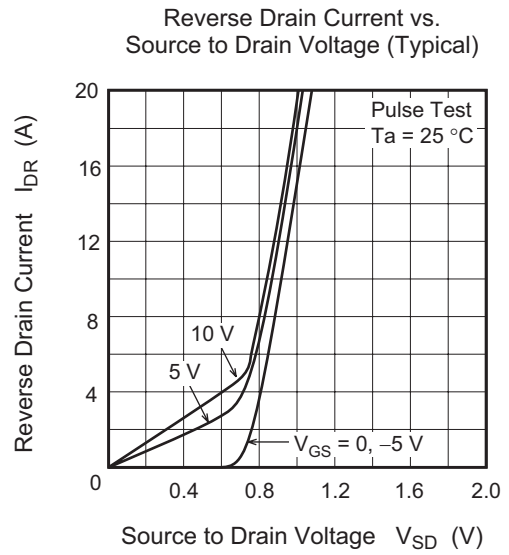
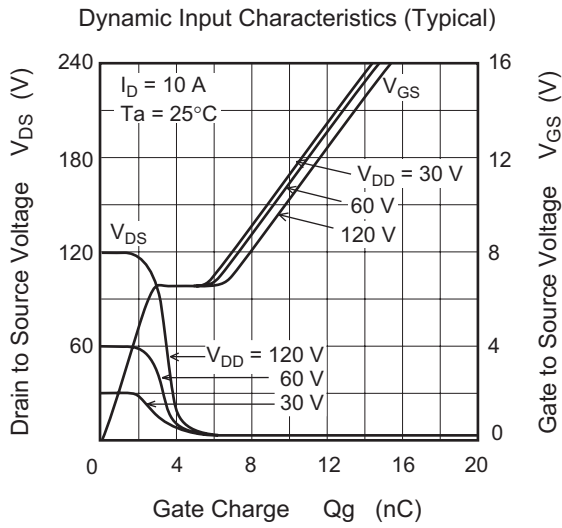
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	150	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 150 \text{ V}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	4.0	6.5	—	S	$I_D = 5 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note4</sup>
Static drain to source on state resistance	$R_{DS(on)}$	—	0.17	0.19	$\Omega$	$I_D = 5 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	430	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	98	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	8	—	pF	
Turn-on delay time	$t_{d(on)}$	—	24	—	ns	$I_D = 5 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 15 \Omega$ $R_g = 10 \Omega$
Rise time	$t_r$	—	31	—	ns	
Turn-off delay time	$t_{d(off)}$	—	43	—	ns	
Fall time	$t_f$	—	8	—	ns	
Total gate charge	$Q_g$	—	9.7	—	nC	$V_{DD} = 120 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 10 \text{ A}$
Gate to source charge	$Q_{gs}$	—	2.7	—	nC	
Gate to drain charge	$Q_{gd}$	—	3.9	—	nC	
Body-drain diode forward voltage	$V_{DF}$	—	0.9	1.4	V	$I_F = 10 \text{ A}$ , $V_{GS} = 0$ <sup>Note4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	90	—	ns	$I_F = 10 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

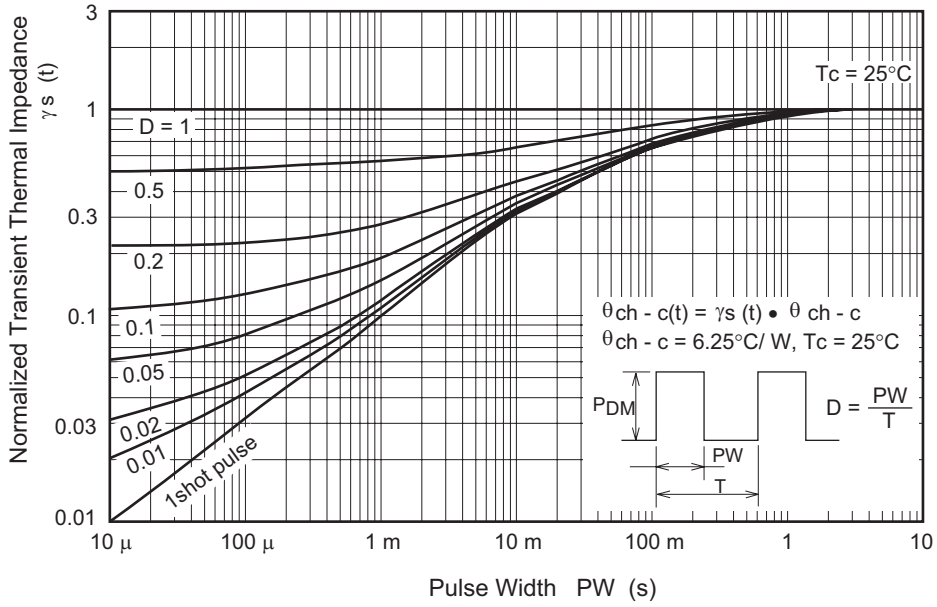
Notes: 4. Pulse test

### Main Characteristics

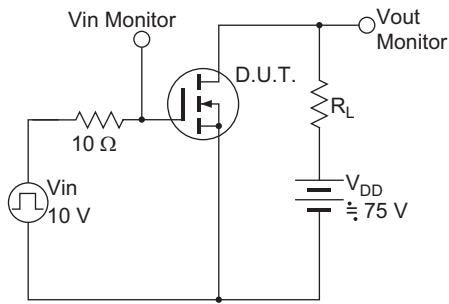




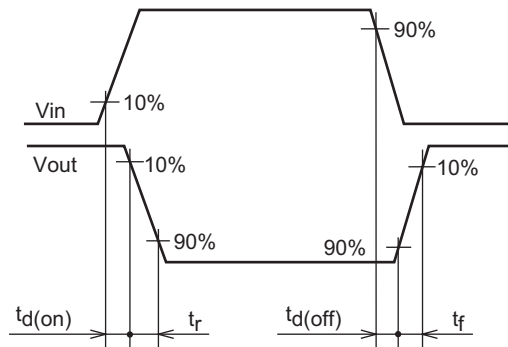
Normalized Transient Thermal Impedance vs. Pulse Width



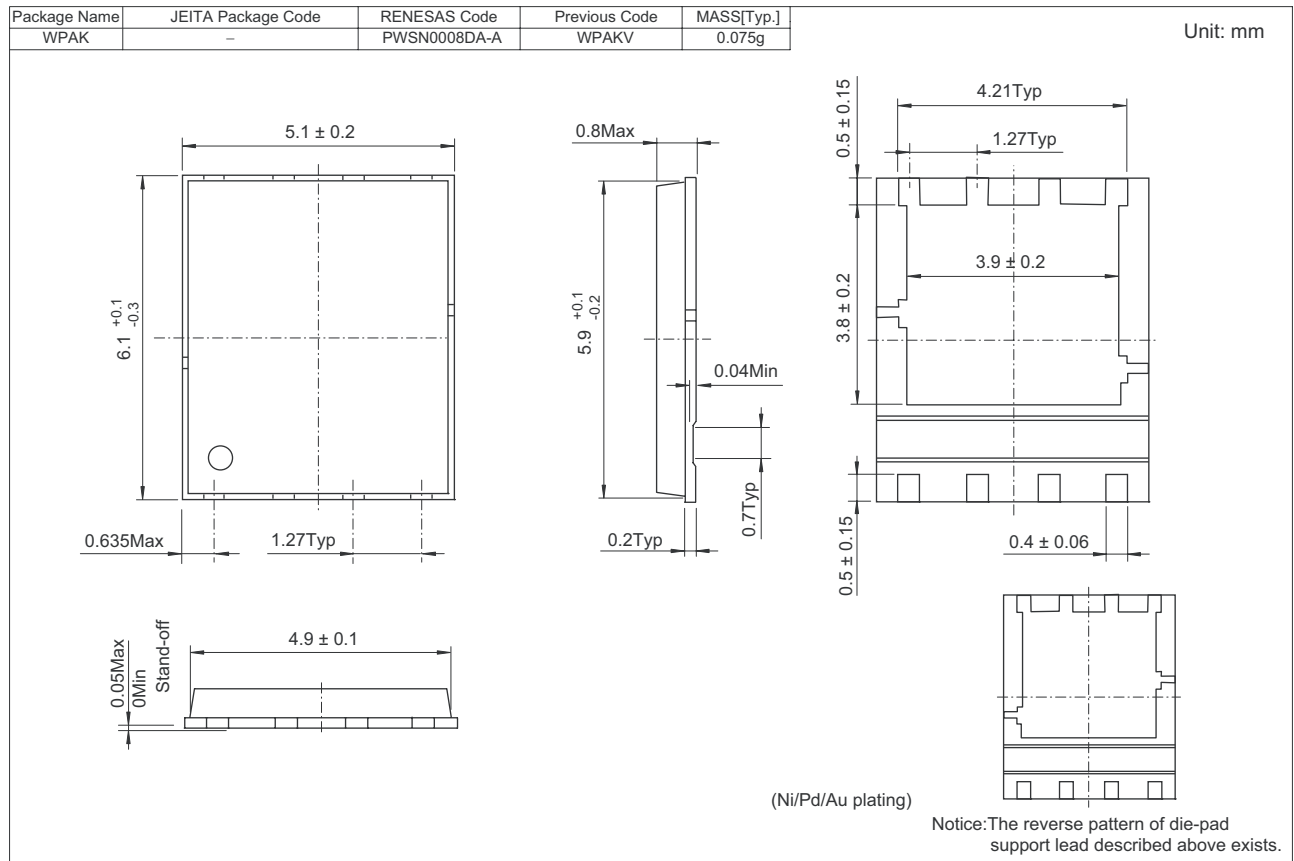
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2185WP-EL-E	2500 pcs, 3000 pcs	Taping

Notes:

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